



L Number	Hits	Search Text	DB	Time stamp
1	32843	flash near2 memor\$3	USPAT;	2003/06/04 11:47
			US-PGPUB;	
			ЛО	
2	53181	nand or nand-\$5	USPAT;	2003/06/04 11:48
			US-PGPUB;	
			JPO	
3	1118	(flash near2 memor\$3) same (nand or nand-\$5)	USPAT;	2003/06/04 11:48
			US-PGPUB;	
	:		ΡΟ	
4	963120	semiconduct\$3 or silicon	USPAT;	2003/06/04 11:48
			US-PGPUB;	
			ЛРО	
5	973	((flash near2 memor\$3) same (nand or nand-\$5)) and (semiconduct\$3 or	USPAT;	2003/06/04 11:48
		silicon)	US-PGPUB;	
1			ΡΟ	
6	132416	implant\$3	USPAT;	2003/06/04 11:48
			US-PGPUB;	
			ЛРО	
7	38453	wordline\$1 or (word adj line\$1)	USPAT;	2003/06/04 11:49
		· · · · · · · · · · · · · · · · · · ·	US-PGPUB;	
			ЛРО	
8	167805	(insulat\$3 or dielectric) with (hole\$1 or via\$1 or opening\$1)	USPAT;	2003/06/04 11:50
			US-PGPUB;	
			ло ́	
9	49310	common near5 source\$1	USPAT;	2003/06/04 11:50
			US-PGPUB;	
			JPO	
10	113	(((flash near2 memor\$3) same (nand or nand-\$5)) and (semiconduct\$3	USPAT;	2003/06/04 11:51
	1	or silicon)) and (wordline\$1 or (word adj line\$1)) and ((insulat\$3 or	US-PGPUB;	
		dielectric) with (hole\$1 or via\$1 or opening\$1)) and (common near5	ЛРО	
		source\$1)		
11	50	implant\$3 and ((((flash near2 memor\$3) same (nand or nand-\$5)) and	USPAT;	2003/06/04 11:51
		(semiconduct\$3 or silicon)) and (wordline\$1 or (word adj line\$1)) and	US-PGPUB;	
		((insulat\$3 or dielectric) with (hole\$1 or via\$1 or opening\$1)) and	JPO	
		(common near5 source\$1))		
12	63	((((flash near2 memor\$3) same (nand or nand-\$5)) and (semiconduct\$3	USPAT;	2003/06/04 11:51
		or silicon)) and (wordline\$1 or (word adj line\$1)) and ((insulat\$3 or	US-PGPUB;	
		dielectric) with (hole\$1 or via\$1 or opening\$1)) and (common near5	JPO	
		source\$1)) not (implant\$3 and ((((flash near2 memor\$3) same (nand or		
		nand-\$5)) and (semiconduct\$3 or silicon)) and (wordline\$1 or (word adj	}	
		line\$1)) and ((insulat\$3 or dielectric) with (hole\$1 or via\$1 or		
		opening\$1)) and (common near5 source\$1)))		